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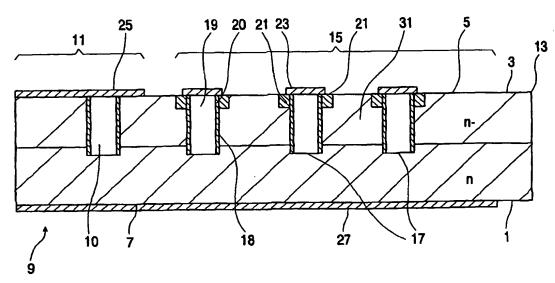
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(54) Title: SEMICONDUCTOR DEVICE WITH EDGE STRUCTURE



(57) Abstract: A semiconductor device has an edge termination region (15) having a plurality of trenches (17). Conductive material (20) and insulating material (19) is formed at the trenches, and surface implants (21) are formed on either side of the trenches. A conductive bridge (23) connects the surface implants (21) to allow equilibrium to be reached in reverse bias.

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According to International Patent Classification (IPC) or to both national classification and IPC

B. FIELDS SEARCHED

Minimum documentation searched (classification system followed by classification symbols) $\ensuremath{\text{IPC}}\xspace 7 \hdots \hdots$

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

Electronic data base consulted during the International search (name of data base and, where practical, search terms used)

EPO-Internal, INSPEC, PAJ

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X Fur	mer documents are used in the continuation of box o.	X Patent family members are liste	ed in annex.
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Category °	Citation of document, with Indication, where appropriate, of the relevant passages	Heisvall to claim No.
A	VAN DALEN R ET AL: "BREAKING THE SILICON LIMIT USING SEMI-INSULATING RESURF LAYERS" PROCEEDINGS OF THE 13TH INTERNATIONAL SYMPOSIUM ON POWER SEMICONDUCTOR DEVICES & ICS (ISPSD '01), OSAKA, JP, 4 - 7 June 2001, pages 391-394, XP001052044 IEEE, NEW YORK, NY, USA ISBN: 4-88686-056-7C figures 1B,1C	1,2,5,6, 9,10
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